TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC4049BP,TC4049BF,TC4049BFN, TC4050BP,TC4050BF,TC4050BFN

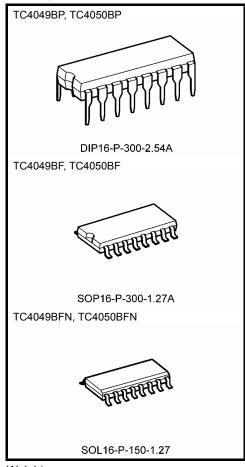
TC4049B Hex Buffer/Converter (inverting type)
TC4050B Hex Buffer/Converter (non-inverting type)

TC4049B, TC4050B contain six circuits of buffers. TC4049B is inverter type and TC4050B is non-inverter type.

Since one TTL or DTL can be directly driven having large output current, these are useful for interfacing from CMOS to TTL or DTL. As voltage up to VSS + 18 volts can be applied to the input regardless of VDD, these can be also used as the level converter IC's which converts CMOS logical circuits of 15 volts or 10 volts system to CMOS/TTL logical circuits of 5 volts system.

Ideal switching characteristic has been obtained by the circuit diagram of three stage inverters for TC4049B and two stage inverters for TC4050B.

Note: xxxFN (JEDEC SOP) is not available in Japan.

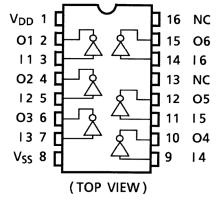


Weight

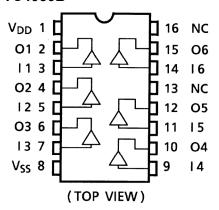
DIP16-P-300-2.54A : 1.00 g (typ.) SOP16-P-300-1.27A : 0.18 g (typ.) SOL16-P-150-1.27 : 0.13 g (typ.)

### **Pin Assignment**

### TC4049B

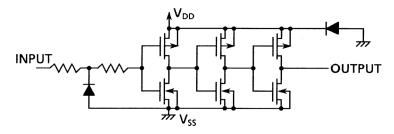


#### **TC4050B**

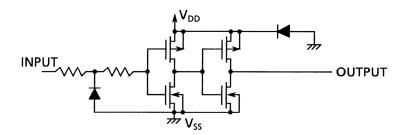


### **Circuit Diagram**

### 1/6 TC4049B



### 1/6 TC4050B



### **Absolute Maximum Ratings (Note)**

Characteristics	Symbol	Rating	Unit
DC supply voltage	$V_{DD}$	V <sub>SS</sub> – 0.5~V <sub>SS</sub> + 20	V
Input voltage	V <sub>IN</sub>	V <sub>SS</sub> – 0.5~V <sub>SS</sub> + 20	V
Output voltage	V <sub>OUT</sub>	V <sub>SS</sub> - 0.5~V <sub>DD</sub> + 0.5	<b>V</b>
DC input current	I <sub>IN</sub>	±10	mA
Power dissipation	PD	300 (DIP)/180 (SOIC)	mW
Operating temperature range	T <sub>opr</sub>	-40~85	°C
Storage temperature range	T <sub>stg</sub>	−65 <b>~</b> 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



# Operating Ranges (V<sub>SS</sub> = 0 V) (Note)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
DC supply voltage	$V_{DD}$	_	3	_	18	V
Input voltage	V <sub>IN</sub>		0	_	18	V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{DD}$  or  $V_{SS}$ .

### Static Electrical Characteristics (V<sub>SS</sub> = 0 V)

		Sym-	Test Condition		-40°C			25°C			85°C		
Charac	teristics	bol		V <sub>DD</sub> (V)	Min	Max	Min	Тур.	Max	Min	Max	Unit	
High-level output		V <sub>OH</sub>	I <sub>OUT</sub>  < 1 μA	5 10	4.95 9.95	_	4.95 9.95	5.00 10.00		4.95 9.95		V	
voltage		-011	$V_{IN} = V_{SS}, V_{DD}$	15	14.95	_	14.95	15.00	_	14.95	_		
			I <sub>OUT</sub>  < 1 μA	5	_	0.05	_	0.00	0.05	_	0.05		
Low-level voltage	output	V <sub>OL</sub>	$V_{IN} = V_{SS}, V_{DD}$	10	_	0.05	_	0.00	0.05	_	0.05	V	
			111 133, 100	15	_	0.05		0.00	0.05	_	0.05		
			V <sub>OH</sub> = 4.6 V	5	-0.73	_	-0.65	-1.2	_	-0.58	_		
			V <sub>OH</sub> = 2.5 V	5	-2.40	_	-2.10	-3.9	_	-1.90	_	mA	
Output hig	h current	IOH	V <sub>OH</sub> = 9.5 V	10	-1.80	_	-1.65	-2.5	_	-1.35	_		
			V <sub>OH</sub> = 13.5 V	15	-4.80	_	-4.30	-8.0	_	-3.50	_		
			$V_{IN} = V_{SS}, V_{DD}$										
		l <sub>OL</sub>	V <sub>OL</sub> = 0.4 V	5	3.8	_	3.2	6.4	_	2.9	_		
Output low	/ current		V <sub>OL</sub> = 0.5 V	10	9.6	_	8.0	16.0	_	6.6	_	mA	
Output 10V	Output low current		V <sub>OL</sub> = 1.5 V	15	28.0	_	24.0	48.0	_	20.0	_	ША	
			$V_{IN} = V_{SS}, V_{DD}$										
		V <sub>IH</sub>	V <sub>OUT</sub> = 0.5 V, 4.5 V	5	3.5	_	3.5	2.75	_	3.5	_	V	
Input high	voltago		V <sub>OUT</sub> = 1.0 V, 9.0 V	10	7.0	_	7.0	5.50	_	7.0	_		
input nign	voltage		V <sub>OUT</sub> = 1.5 V, 13.5 V	15	11.0	_	11.0	8.25	_	11.0	_	V	
			$ I_{OUT}  < 1 \mu A$										
			V <sub>OUT</sub> = 0.5 V, 4.5 V	5		1.5	_	2.25	1.5	_	1.5		
Input low y			V <sub>OUT</sub> = 1.0 V, 9.0 V	10	_	3.0	_	4.50	3.0	_	3.0	V	
Input low voltage		V <sub>IL</sub>	V <sub>OUT</sub> = 1.5 V, 13.5 V	15	_	4.0	_	6.75	4.0	_	4.0		
		$ I_{OUT}  < 1 \mu A$											
Input	"H" level	l <sub>IH</sub>	V <sub>IH</sub> = 18 V	18	_	0.1	_	10 <sup>-5</sup>	0.1	_	1.0		
current	"L" level	I <sub>IL</sub>	V <sub>IL</sub> = 0 V	18	_	-0.1	_	$-10^{-5}$	-0.1	_	-1.0	μΑ	
			V V. V. V.	5	_	1	_	0.002	1	_	30		
Quiescent supply current		I <sub>DD</sub>	$V_{IN} = V_{SS}, V_{DD}$ (Note)	10	_	2	_	0.004	2	_	60	μА	
			(Note)	15	_	4	—	0.008	4	_	120		

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Note: All valid input combinations.

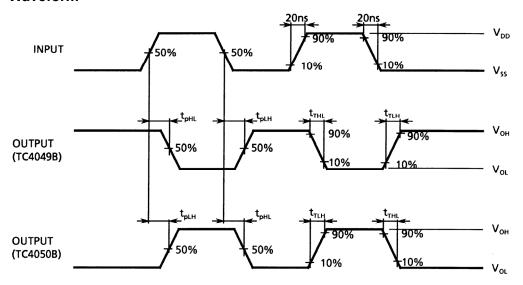


# Dynamic Electrical Characteristics (Ta = 25°C, $V_{SS}$ = 0 V, $C_L$ = 50 pF)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit	
	Characteristics	Symbol		V <sub>DD</sub> (V)	IVIIII	ιyp.	IVIAX	Offic
Outr	out transition time			5	_	60	160	
	to high)	t <sub>TLH</sub>	_	10	_	30	80	ns
(IOW	to riigir)			15	_	25	60	
Outr	out transition time			5	_	120	60	
	n to low)	t <sub>THL</sub>	_	10	_	10	40	ns
(High	1 to low)			15	_	8	30	
	Propagation delay time			5	_	60	120	
_	(low to high)	t <sub>pLH</sub>	_	10	_	35	65	ns
49B	(low to riigir)			15	_	30	50	
TC4049B	Propagation delay time			5	_	40	60	
' '	(high to low)	t <sub>pHL</sub>	_	10	_	20	30	ns
	(riigir to low)			15	_	15	20	
	Propagation delay time			5	_	50	130	
	(low to high)	t <sub>pLH</sub>	_	10	_	30	70	ns
TC4050B				15	_	25	55	
	Propagation delay time (high to low)			5	_	30	70	
		t <sub>pHL</sub>	_	10	_	17	35	ns
	(iligit to low)			15	_	14	25	
Inpu	t capacitance	C <sub>IN</sub>	_	_	5	7.5	pF	

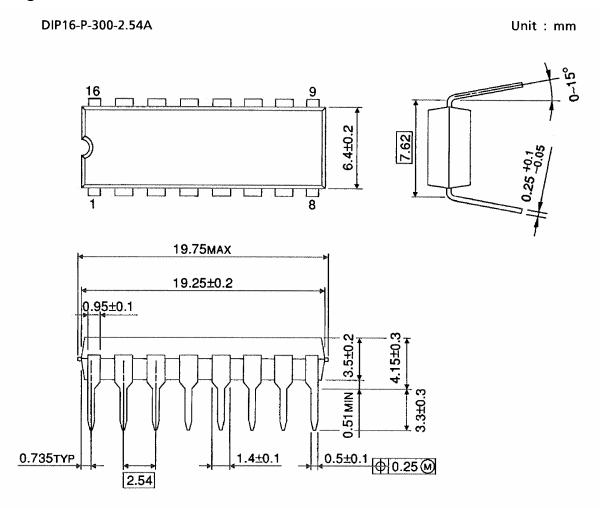
# **Waveform for Measurement of Dynamic Characteristics**

### Waveform





# **Package Dimensions**

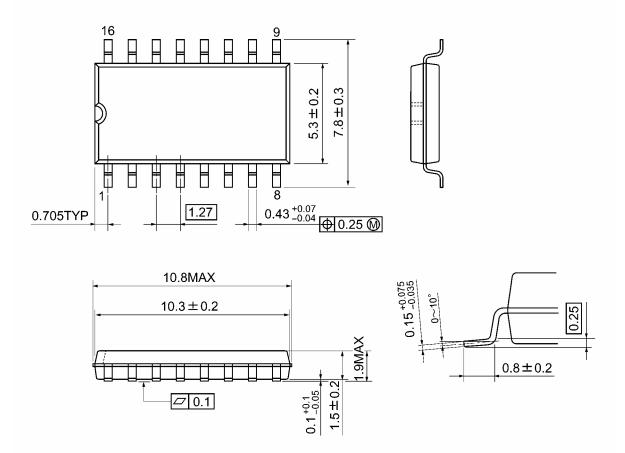


Weight: 1.00 g (typ.)



# **Package Dimensions**

SOP16-P-300-1.27A Unit: mm

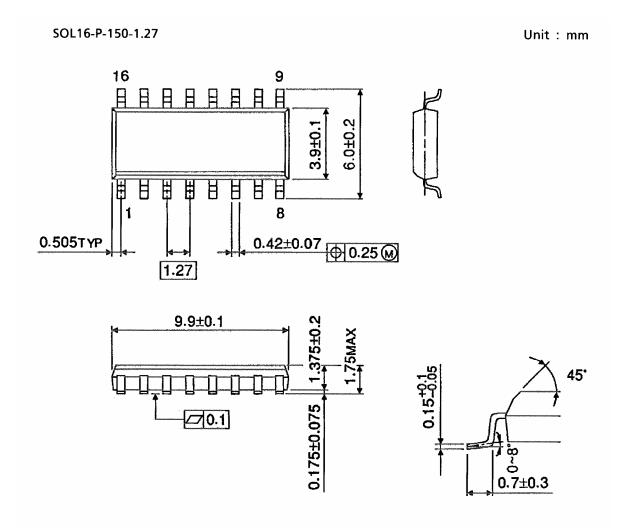


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Weight: 0.18 g (typ.)



# **Package Dimensions (Note)**



Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

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20070701-EN GENERAL

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